NSN 5961-01-174-4472

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-174-4472 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **End Application:** An/alq-165 **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 30.0 reverse voltage, peak all semiconductor device diode **Current Rating Per Characteristic:** 20.00 milliamperes forward current, dc all semiconductor device diode and 100.00 microamperes reverse current, dc all semiconductor device diode **Power Rating Per Characteristic:** 300.0 milliwatts total power dissipation all semiconductor device diode **Capacitance Rating In Picofarads:** 1.0 all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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